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August 2008

Single-Channel: 6N138, 6N139 Dual-Channel: HCPL2730, HCPL2731 Low Input Current High Gain Split Darlington Optocouplers

Features

- Low current 0.5mA
- Superior CTR-2000%
- Superior CMR-10kV/µs
- CTR guaranteed 0–70°C
- U.L. recognized (File # E90700)
- VDE recognized (File # 120915) Ordering option V, e.g., 6N138V
- Dual Channel HCPL2730, HCPL2731

Applications

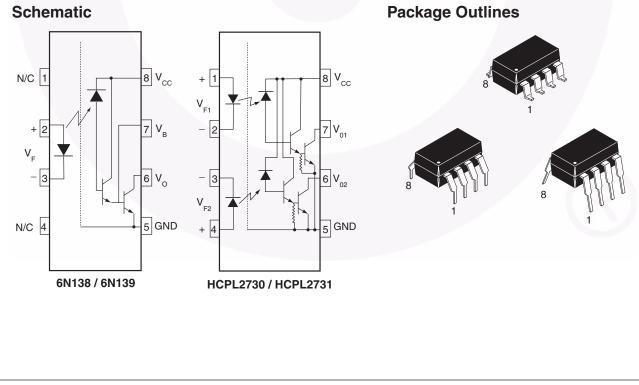
- Digital logic ground isolation
- Telephone ring detector
- EIA-RS-232C line receiver
- High common mode noise line receiver
- µP bus isolation
- Current loop receiver

Description

The 6N138/9 and HCPL2730/HCPL2731 optocouplers consist of an AlGaAs LED optically coupled to a high gain split darlington photodetector.

The split darlington configuration separating the input photodiode and the first stage gain from the output transistor permits lower output saturation voltage and higher speed operation than possible with conventional darlington phototransistor optocoupler. In the dual channel devices, HCPL2730/HCPL2731, an integrated emitter-base resistor provides superior stability over temperature.

The combination of a very low input current of 0.5mA and a high current transfer ratio of 2000% makes this family particularly useful for input interface to MOS, CMOS, LSTTL and EIA RS232C, while output compatibility is ensured to CMOS as well as high fan-out TTL requirements. An internal noise shield provides exceptional common mode rejection of 10 kV/µs.



Absolute Maximum Ratings ($T_A = 25^{\circ}C$ unless otherwise specified) Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter		Value	Units
T _{STG}	Storage Temperature		-55 to +125	°C
T _{OPR}	Operating Temperature		-40 to +85	°C
T _{SOL}	Lead Solder Temperature (Wave solder only. See recomingraph for SMD mounting)	260 for 10 sec	°C	
EMITTER				
I _F (avg)	DC/Average Forward Input Current	Each Channel	20	mA
I _F (pk)	Peak Forward Input Current (50% duty cycle, 1 ms P.W.)	40	mA	
I _F (trans)	Peak Transient Input Current - (≤1µs P.W., 300 pps)	1.0	Α	
V _R	Reverse Input Voltage	Each Channel	5	V
PD	Input Power Dissipation	35	mW	
DETECTO	R			
I _O (avg)	Average Output Current	Each Channel	60	mA
V _{ER}	Emitter-Base Reverse Voltage 6N138 and		0.5	V
V _{CC} , V _O	Supply Voltage, Output Voltage	-0.5 to 7	V	
		6N139, HCPL2731	-0.5 to 18	
Po	Output Power Dissipation	Each Channel	100	mW

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Electrical Characteristics (T _A	c = 0 to 70°C unless otherwise specified)
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Individual Component Characteristics

Symbol	Parameter	Test Cond	litions	Device	Min.	Typ.*	Max.	Unit
EMITTER	1	1		1	I	1	1	
V _F	Input Forward Voltage		$T_A = 25^{\circ}C$	All		1.30	1.7	V
		Each channel ($I_F = 1.6$	SmA)	-			1.75	
BV _R	Input Reverse Breakdown Voltage	$T_{A} = 25^{\circ}C, I_{R} = 10\mu A$		All	5.0	20		V
$\Delta V_{F} / \Delta T_{A}$	Temperature Coefficient of Forward Voltage	I _F = 1.6mA		All		-1.8		mV/°C
DETECTO	R							
I _{OH}	Logic HIGH Output	$I_{\rm F} = 0 {\rm mA}, V_{\rm O} = V_{\rm CC} = 18 {\rm V}$		6N139		0.01	100	μA
	Current		Each Channel	HCPL2731				
		$I_F = 0mA, V_O = V_{CC} =$	7V	6N138		0.01	250	
			Each Channel	HCPL2730				
I _{CCL}	Logic LOW supply	I _F = 1.6mA, V _O = Open, V _{CC} = 18V		6N138, 6N139		0.4	1.5	mA
		$I_{F1} = I_{F2} = 1.6 \text{mA}, V_{C}$	I _{F1} = I _{F2} = 1.6mA, V _{CC} = 18V			1.3	3	
		$V_{O1} - V_{O2} = Open, V_{CC} = 7V$		HCPL2730				
I _{CCH} Logic HIGH Supply		I _F = 0mA, V _O = Open,	V _{CC} = 18V	6N138, 6N139		0.05	10	μA
		$I_{F1} = I_{F2} = 0mA, V_{CC}$	= 18V	HCPL2731		0.10	20	
		V _{O1} – V _{O2} = Open, V _C	$c_{\rm C} = 7V$	HCPL2730				

Transfer Characteristics

Symbol	Parameter	Test Conditions		Device	Min.	Тур.*	Max.	Unit
COUPLE	D							
CTR Current Transfer		I _F = 0.5mA, V _O = 0.4 \	$I_F = 0.5 \text{mA}, V_O = 0.4 \text{ V}, V_{CC} = 4.5 \text{V}$		400	1100		%
	Ratio ⁽¹⁾⁽²⁾		Each Channel	HCPL2731		3500		
		I _F = 1.6mA, V _O = 0.4 \	/, V _{CC} = 4.5V	6N139	500	1300		
		Each Channel	HCPL2731		2500			
		$I_{\rm F} = 1.6 {\rm mA}, V_{\rm O} = 0.4 {\rm V}$	/, V _{CC} = 4.5V	6N138	300	1300		
			Each Channel	HCPL2730]	2500		
V _{OL}	Logic LOW Output	I _F = 0.5mA, I _O = 2mA,	$V_{CC} = 4.5V$	6N139		0.08	0.4	V
	Voltage ⁽²⁾	I _F = 1.6mA, I _O = 8mA,	$V_{CC} = 4.5V$	6N139		0.01	0.4	
		Each Channel	HCPL2731					
		I _F = 0.5mA, I _O = 15mA	A, $V_{CC} = 4.5V$	6N139		0.13	0.4	
		Each Channel	HCPL2731					
		$I_{\rm F} = 12$ mA, $I_{\rm O} = 24$ mA	, V _{CC} = 4.5V	6N139		0.20	0.4	
			Each Channel	HCPL2731				
		I _F = 1.6mA, I _O = 4.8m	A, V _{CC} = 4.5V	6N138		0.10	0.4	
			Each Channel	HCPL2730				

*All Typicals at $T_A = 25^{\circ}C$

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Electrical Characteristics	(Continued) (T _A = 0 to 70°C unless otherwise specified)
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Switching Characteristics ($V_{CC} = 5V$)

Symbol	Parameter	Test Condit	tions	Device	Min.	Тур.*	Max.	Uni	
T _{PHL}	Propagation Delay	$R_L = 4.7\Omega, I_F = 0.5mA$		6N139			30	μs	
	Time to Logic LOW ⁽²⁾ (Fig. 24)		$T_A = 25^{\circ}C$	1		4	25		
	LOW (Fig. 24)	$R_L = 4.7\Omega, I_F = 0.5mA$		HCPL2731			120		
		Each Channel	$T_A = 25^{\circ}C$	1		3	100		
		$R_{L} = 270\Omega, I_{F} = 12mA$		6N139			2		
			$T_A = 25^{\circ}C$	1		0.2	1		
		$R_L = 270\Omega, I_F = 12mA, E$	ach Channel	HCPL2730			3		
			$T_A = 25^{\circ}C$	HCPL2731		0.3	2		
		$R_L = 2.2\Omega, I_F = 1.6mA$		6N138			15		
			$T_A = 25^{\circ}C$			1.5	10		
		$R_L = 2.2\Omega, I_F = 1.6mA, E$	Each Channel	HCPL2731			25		
			$T_A = 25^{\circ}C$	HCPL2730		1	20		
T _{PLH}	Propagation Delay	$R_{L} = 4.7\Omega, I_{F} = 0.5mA$	1	6N139			90	μs	
	Time to Logic		Each Channel	HCPL2731					
	HIGH ⁽²⁾ (Fig. 24)	$R_L = 4.7\Omega, I_F = 0.5m$	$R_L = 4.7\Omega, I_F = 0.5mA, T$	_A = 25°C	6N139		12	60	1
			Each Channel	HCPL2731		22	1		
		$R_{L} = 270\Omega, I_{F} = 12mA$		6N139			10		
			$T_A = 25^{\circ}C$	1		1.3	7		
		$R_{L} = 270\Omega, I_{F} = 12mA, E$	Each Channel	HCPL2730			15		
			$T_A = 25^{\circ}C$	HCPL2731		5	10		
		$R_L = 2.2\Omega, I_F = 1.6mA$		6N138			50		
			Each Channel	HCPL2730/1					
		$R_L = 2.2\Omega, I_F = 1.6mA, T$	_A = 25°C	6N138		7	35		
			Each Channel	HCPL2730/1		16	1		
ICM _H I Common Mode Transient		$I_{F} = 0mA, V_{CM} = 10V_{P-}$ $R_{L} = 2.2\Omega$	_P , T _A = 25°C,	6N138 6N139	1,000	10,000		V/µ	
	Immunity at Logic HIGH ⁽³⁾ (Fig. 25)		Each Channel	HCPL2730 HCPL2731					
ICMLI	Common Mode Transient	$(I_F = 1.6mA, V_{CM} = 10V)$ $T_A = 25^{\circ}C$	/ _{P-B} , R _L = 2.2Ω)	6N138 6N139	1,000	10,000		V/µ	
Immunity at Logic LOW ⁽³⁾ (Fig. 25)			Each Channel	HCPL2730 HCPL2731					

** All Typicals at $T_A = 25^{\circ}C$

Electrical Characteristics (Continued) (T_A = 0 to 70°C unless otherwise specified)

Isolation Characteristics

Symbol	Characteristics	Test Conditions	Min.	Тур.*	Max.	Unit
I _{I-O}	Input-Output Insulation Leakage Current ⁽⁴⁾	Relative humidity = 45%, T_A = 25°C, t = 5s, V _{I-O} = 3000VDC			1.0	μA
V _{ISO}	Withstand Insulation Test Voltage ⁽⁴⁾	$\label{eq:rescaled} \begin{array}{l} RH \leq 50\%, T_{A} = 25^\circ C, I_{I\text{-}O} \leq 2\muA, \\ t = 1 \text{ min.} \end{array}$	2500			V _{RMS}
R _{I-O}	Resistance (Input to Output) ⁽⁴⁾	V _{I-O} = 500VDC		10 ¹²		Ω
C _{I-O}	Capacitance (Input to Output) ⁽⁴⁾⁽⁵⁾	f = 1MHz		0.6		pF
II-I	Input-Input Insulation Leakage Current ⁽⁶⁾	$\label{eq:RH} \begin{array}{l} RH \leq 45\%, V_{I\text{-}I} = 500 \text{VDC}, t = 5s, \\ HCPL2730/2731 only \end{array}$		0.005		μA
R _{I-I}	Input-Input Resistance ⁽⁶⁾	V _{I-I} = 500VDC, HCPL2730/2731 only		10 ¹¹		Ω
C _{I-I}	Input-Input Capacitance ⁽⁶⁾	f = 1MHz, HCPL2730/2731 only		0.03		pF

*All Typicals at $T_A = 25^{\circ}C$

Notes:

- 1. Current Transfer Ratio is defined as a ratio of output collector current, I_O, to the forward LED input current, I_F, times 100%.
- 2. Pin 7 open. (6N138 and 6N139 only)
- 3. Common mode transient immunity in logic HIGH level is the maximum tolerable (positive) dV_{cm}/dt on the leading edge of the common mode pulse signal V_{CM} , to assure that the output will remain in a logic HIGH state (i.e., $V_O > 2.0V$). Common mode transient immunity in logic LOW level is the maximum tolerable (negative) dV_{cm}/dt on the trailing edge of the

common mode pulse signal, V_{CM} , to assure that the output will remain in a logic LOW state (i.e., $V_O < 0.8V$).

- 4. Device is considered a two terminal device: Pins 1, 2, 3 and 4 are shorted together and Pins 5, 6, 7 and 8 are shorted together.
- 5. For dual channel devices, C_{I-O} is measured by shorting pins 1 and 2 or pins 3 and 4 together and pins 5 through 8 shorted together.
- 6. Measured between pins 1 and 2 shorted together, and pins 3 and 4 shorted together.

Electrical Characteristics (Continued) $T_A = 25^{\circ}C$ unless otherwise specified)

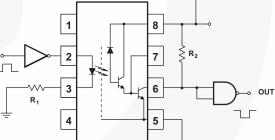
Current Limiting Resistor Calculations

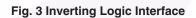
 R_1 (Non-Invert) = $V_{DD1} - V_{DF} - V_{OL1}$ OUTPUT le. CMOS CMOS INPUT R1 (V) 74XX 74LXX 74SXX 74LSXX 74HXX $R_1 \text{ (Invert)} = V_{DD1} - V_{OH1} - V_{DF}$ @ 5V @ 10V R2 (V) $\mathsf{R}_2 = \frac{\mathsf{V}_{\mathsf{DD2}} = \mathsf{V}_{\mathsf{OLX}} \ (@ \ \mathsf{I}_\mathsf{L} - \mathsf{I}_2)}{\mathsf{I}_\mathsf{I}}$ CMOS NON-INV. 2000 1000 2200 750 1000 1000 1000 560 @ 5V INV. 510 CMOS NON-INV. 5100 @ 10V INV. 4700 Where: NON-INV. 2200 74XX V_{DD1} = Input Supply Voltage INV. V_{DD2} = Output Supply Voltage 180 V_{DF} = Diode Forward Voltage 74LXX NON-INV. 1800 V_{OL1} = Logic "0" Voltage of Driver INV. 100 V_{OH1} = Logic "1" Voltage of Driver NON-INV. 2000 74SXX I_F = Diode Forward Current INV. 360 V_{OLX} = Saturation Voltage of 74LSXX NON-INV. 2000 Output Transistor INV. 180 I_I = Load Current Through 74HXX NON-INV. 2000 **Resistor R2** I₂ = Input Current of Output Gate INV. 180

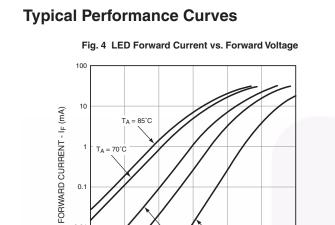
Fig. 2 Non-Inverting Logic Interface

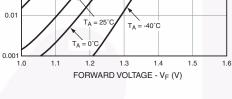


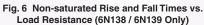
Fig. 1 Resistor Values for Logic Interface

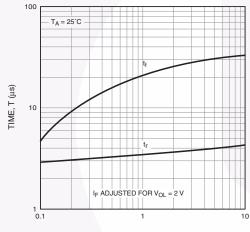






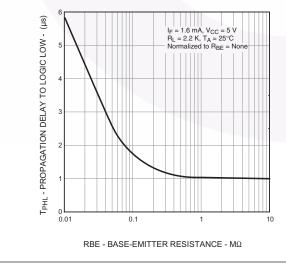






R_L - LOAD RESISTANCE (kΩ)

Fig. 8 Propagation Delay To Logic Low vs. Base-Emitter Resistance (HCPL2730 / HCPL2731 Only)



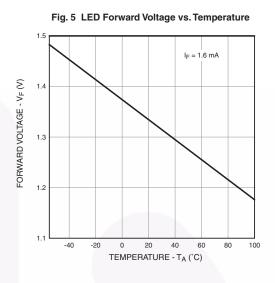


Fig. 7 Non-saturated Rise and Fall Times vs. Load Resistance (HCPL2730 / HCPL2731 Only)

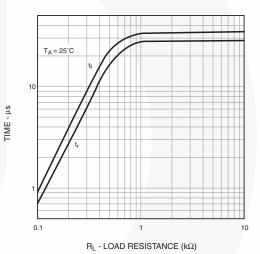
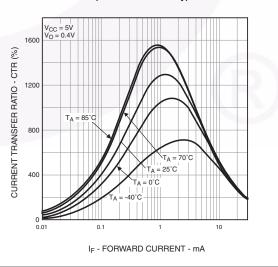
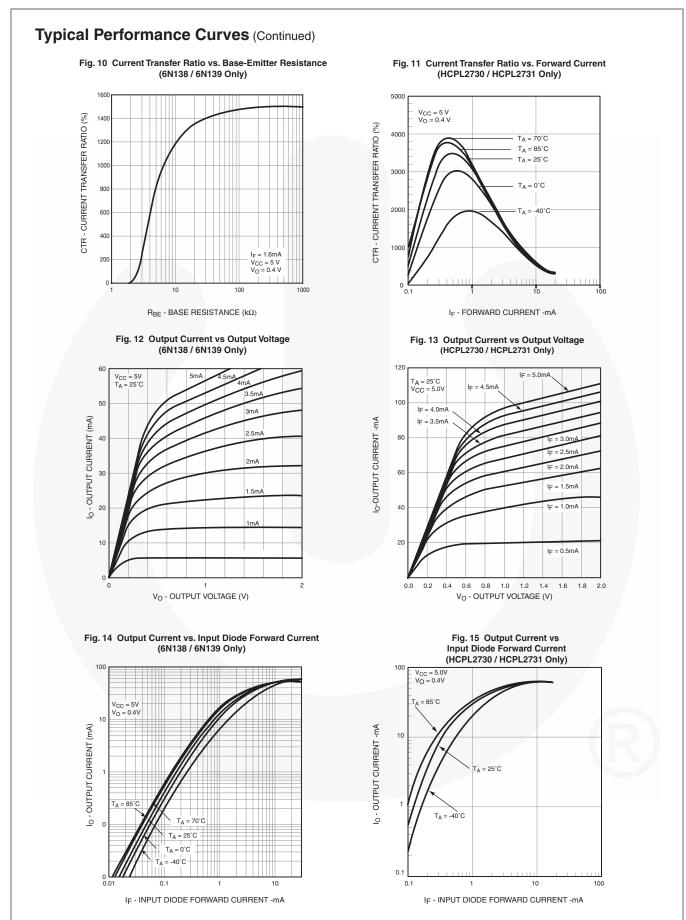
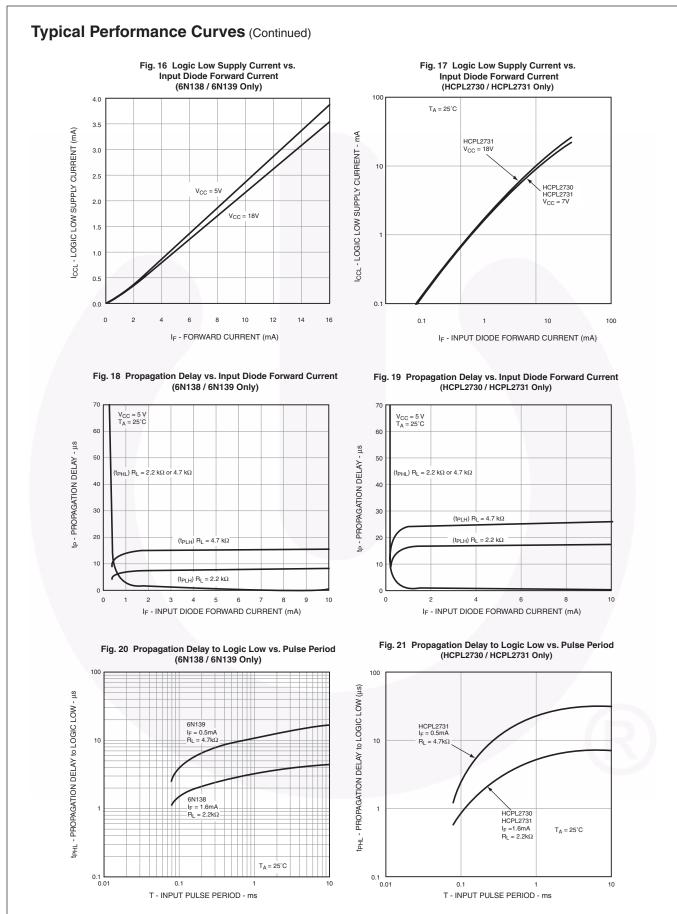
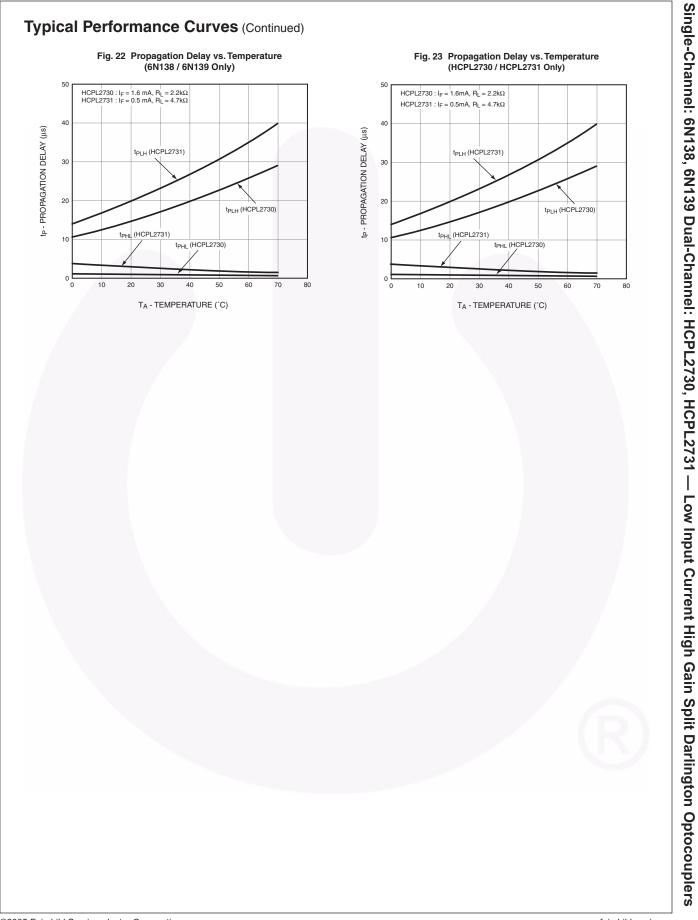


Fig. 9 Current Transfer Ratio vs. Forward Current (6N138 / 6N139 Only)

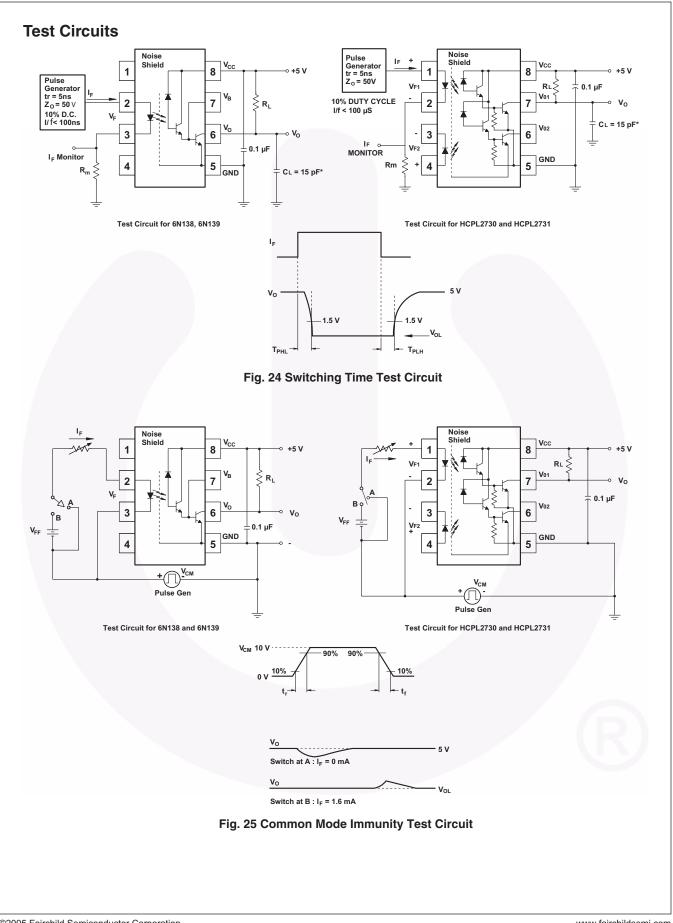








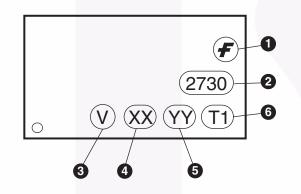
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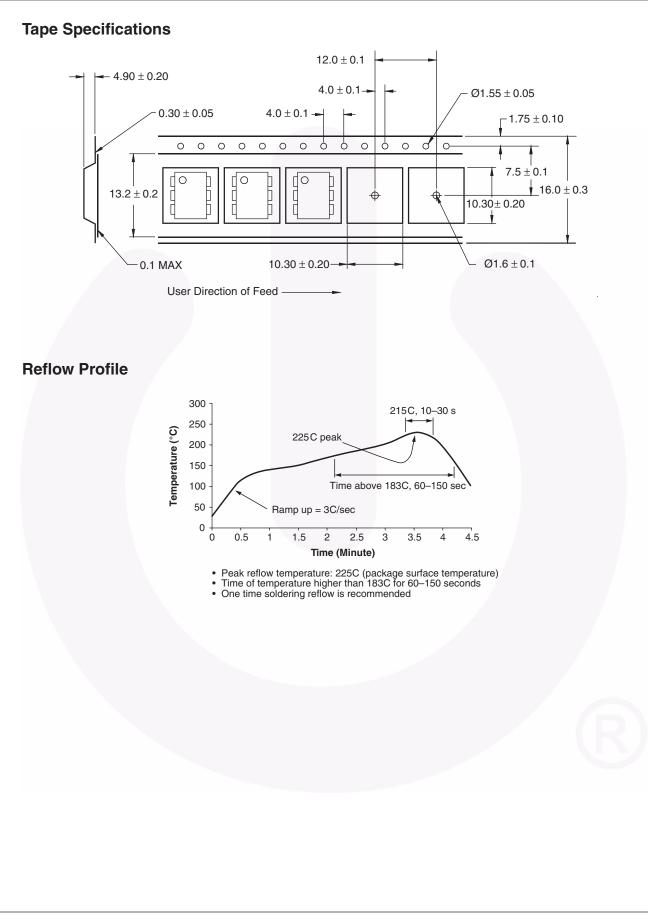
Ordering Information

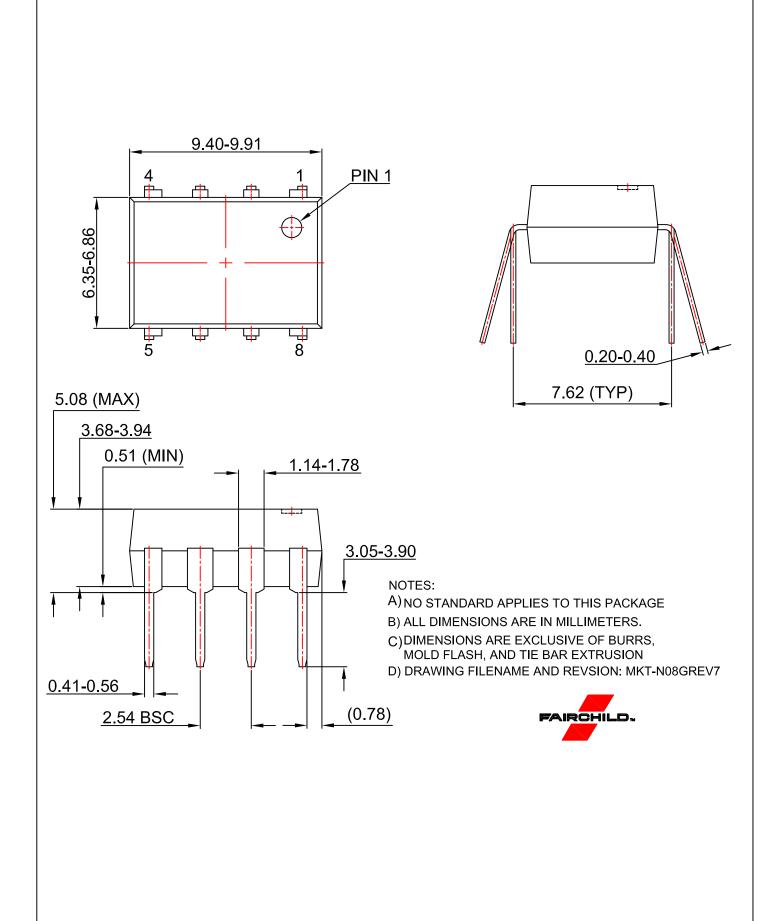
Option	Example Part Number	Description
No Suffix	6N138	Standard Through Hole Device, 50 pcs per tube
S	6N138S	Surface Mount Lead Bend
SD	6N138SD	Surface Mount; Tape and reel
W	6N138W	0.4" Lead Spacing
V	6N138V	VDE0884
WV	6N138WV	VDE0884; 0.4" lead spacing
SV	6N138SV	VDE0884; surface mount
SDV	6N138SDV	VDE0884; surface mount; tape and reel

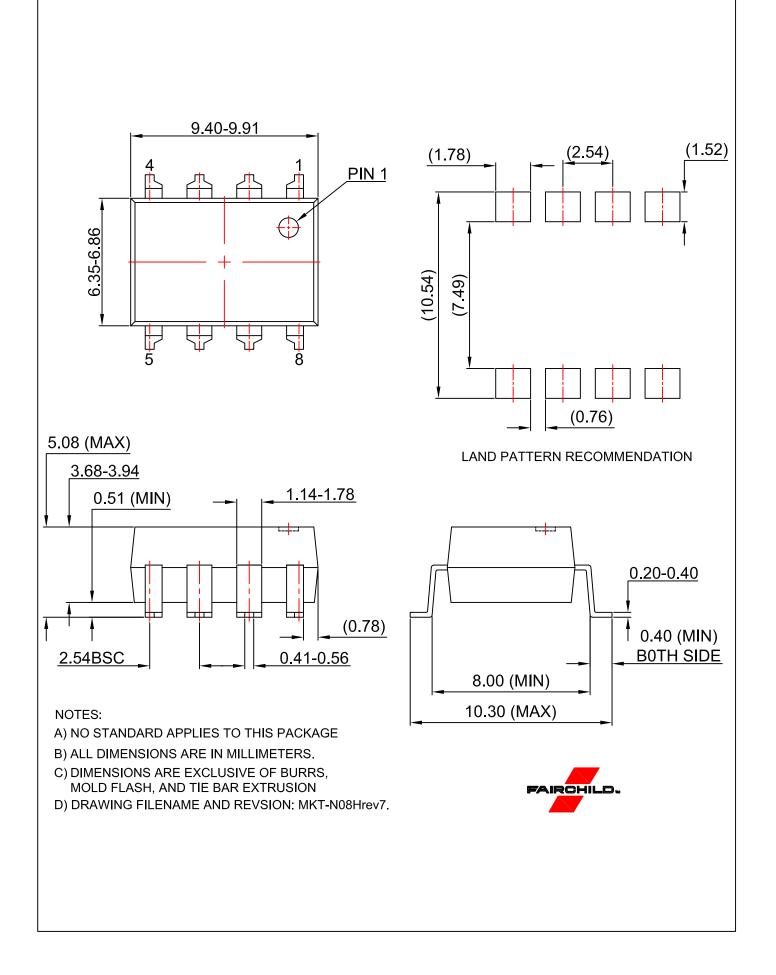
Marking Information



Definitions					
1	Fairchild logo				
2	Device number				
3	VDE mark (Note: Only appears on parts ordered with VDE option – See order entry table)				
4	Two digit year code, e.g., '07'				
5	5 Two digit work week ranging from '01' to '53'				
6	Assembly package code				









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Definition of Terms		
Datasheet Identification	Product Status	Definition
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.

Rev. 177

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